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تهران، پاساژ امجد، طبقه اول، واحد ۱۶



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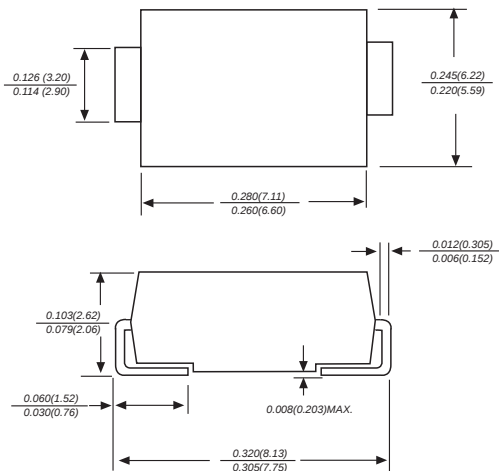


SS32 THRU SS3200

SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

Reverse Voltage - 20 to 200 Volts Forward Current - 3.0 Amperes

DO-214AB/SMC



Dimensions in inches and (millimeters)

FEATURES

- ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- ◆ For surface mounted applications
- ◆ Low reverse leakage
- ◆ Built-in strain relief, ideal for automated placement
- ◆ High forward surge current capability
- ◆ High temperature soldering guaranteed: 250°C/10 seconds at terminals

MECHANICAL DATA

Case: JEDEC DO-214AB molded plastic body
Terminals: Solder plated, solderable per MIL-STD-750, Method 2026
Polarity: Color band denotes cathode end
Mounting Position: Any
Weight: 0.007 ounce, 0.25grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.
Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

MDD Catalog Number	SYMBOLS	SS32	SS33	SS34	SS35	SS36	SS38	SS310	SS3150	SS3200	UNITS
Maximum repetitive peak reverse voltage	V _{RRM}	20	30	40	50	60	80	100	150	200	VOLTS
Maximum RMS voltage	V _{RMS}	14	21	28	35	42	56	70	105	150	VOLTS
Maximum DC blocking voltage	V _{DC}	20	30	40	50	60	80	100	150	200	VOLTS
Maximum average forward rectified current at T _L (see fig.1)	I _{AV}	3.0									Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	100.0									Amps
Maximum instantaneous forward voltage at 3.0A	V _F	0.55			0.70		0.85			0.95	Volts
Maximum DC reverse current T _A =25°C at rated DC blocking voltage T _A =100°C	I _R	0.5							0.2		mA
		20				10		2.0			
Typical junction capacitance (NOTE 1)	C _J	500			300						pF
Typical thermal resistance (NOTE 2)	R _{θJA}	55.0									°C/W
Operating junction temperature range	T _J	-50 to +125					-50 to +150				°C
Storage temperature range	T _{STG}	-50 to +150									°C

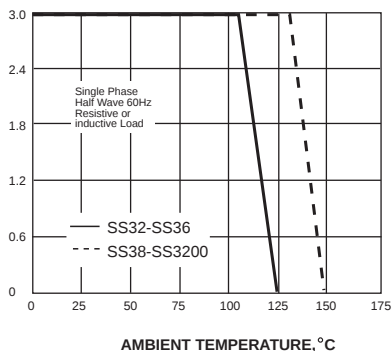
Note: 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
2. P.C.B. mounted with 0.2x0.2" (5.0x5.0mm) copper pad areas

MDD ELECTRONIC

RATINGS AND CHARACTERISTIC CURVES SS32 THRU SS3200

AVERAGE FORWARD RECTIFIED CURRENT,
AMPERES

FIG. 1- FORWARD CURRENT DERATING CURVE



PEAK FORWARD SURGE CURRENT,
AMPERES

FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

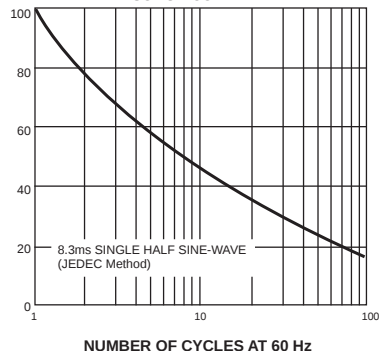


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

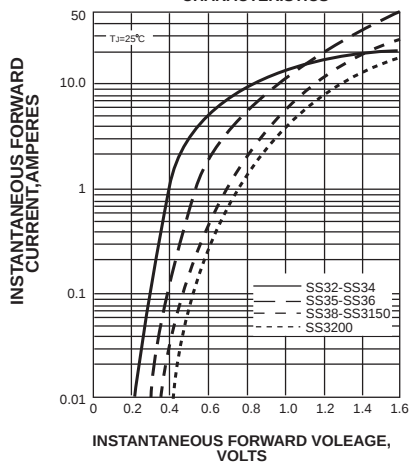


FIG. 4-TYPICAL REVERSE CHARACTERISTICS

INSTANTANEOUS REVERSE CURRENT,
MILLIAMPERES

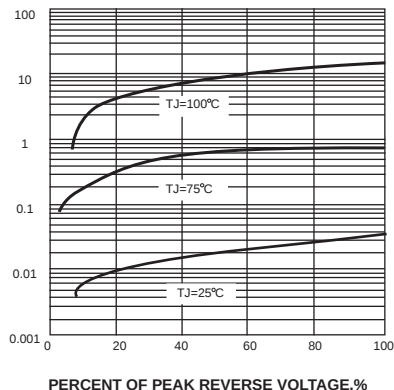
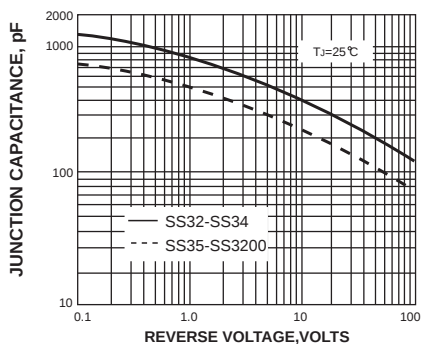


FIG. 5-TYPICAL JUNCTION CAPACITANCE



TRANSIENT THERMAL IMPEDANCE,
°C/W

FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE

